

S.E (Electrical) Sem-III Choice Based

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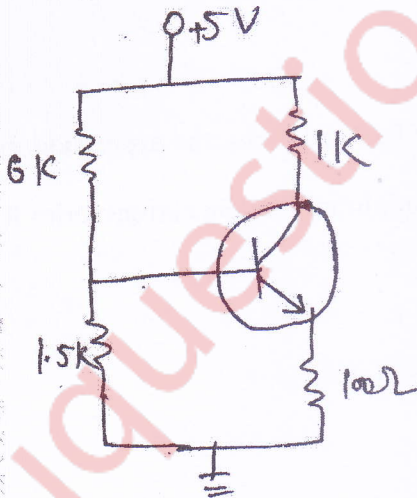
[Time: 3 Hours]

[Marks: 80]

Please check whether you have got the right question paper.

- N.B:
1. Question No 1. is compulsory.
  2. Attempt **any three** from the rest.
  3. Write neat and clean
  4. Writing answer directly for numerical will not be considered for marks allotment
  5. Assume any suitable data wherever required.

- Q.1** Answer any four (20)
- a) Explain input and output characteristic of FET.
  - b) Explain the ripple factor in case of center tapped full wave rectifier with C filter.
  - c) Explain the Nyquist criteria of oscillation.
  - d) Explain voltage shunt current feedback amplifier.
  - e) Explain enhancement type MOSFET.
- Q.2** (a) Explain collpit oscillator with the help of suitable circuit diagram. Derive the expressing of frequency for oscillation and necessary condition for oscillation. (10)
- (b) Explain double biased clipper with the help of suitable circuit and waveform. (10)
- Q.3** (a) For the given circuit find steady state DC parameters  $I_{CQ}$  and  $V_{CEQ}$ . Given  $\beta = 100$  and  $V_{be} = 0.7v$ . Also state in which region the circuit in working. (10)



- (b) Derive the expressing for stabilization factors for voltage divider biased circuit of BJT. (10)

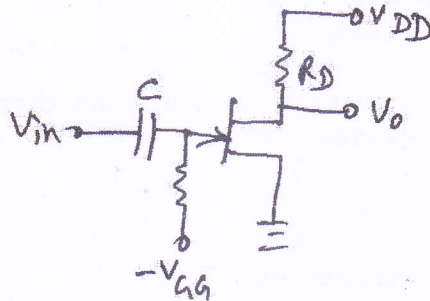


S.E.C (Electrical) Sem-III Choice Based

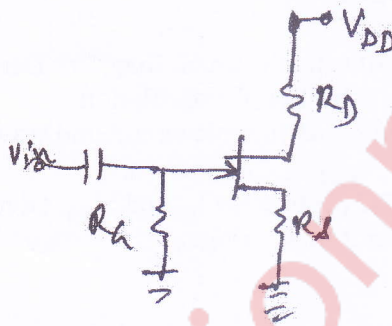
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- Q.4 (a) Draw the circuit diagram of cascade and cascode amplifiers and differentiate it. (10)  
 (b) Given  $V_{GG} = 1.5V$ ,  $V_{DD} = 15V$ ,  $R_D = 1.5k\Omega$ ,  $R_G = 1.5k\Omega$ ,  $I_{DSS} = 15mA$ ,  $V_P = -4V$ . Determine  $V_{GS}$  and  $I_D$  and  $V_{DS}$ . (05)



- (c) In JEET circuit show with self bias  $V_{DD} = 25V$ ,  $R_D = 3k\Omega$ ,  $R_S = 400\Omega$ ,  $I_D = 2mA$ . Determine  $V_{DS}$  and  $V_{GS}$ . (05)



- Q.5 (a) Draw and explain the h-parameter model of BJT and derive the expression for  $A_v$ ,  $A_i$ ,  $R_i$ . Consider CE configuration. (10)

- (b) Explain various configuration of feedback amplifier. Explain current series feedback in detail. (10)

- Q.6 Write short note on any two (20)

- (a) Thermal runaway in BJT and FET  
 (b)  $r_e$  model of BJT  
 (c) RC phase shift oscillator.